

## 10-Line to 4-Line BCD Priority Encoder

High-Voltage Types (20-Volt Rating)

■ CD40147B CMOS encoder features priority encoding of the inputs to ensure that only the highest-order data line is encoded. Ten data input lines (0-9) are encoded to four-line (8,4,2,1) BCD. The highest priority line is line 9. All four output lines are logic 1 ( $V_{SS}$ ) when all input lines are logic 0. All inputs and outputs are buffered, and each output can drive one TTL low-power Schottky load. The CD40147B is functionally similar to the TTL 54/74147 if pin 15 is tied low. The CD40147B types are supplied in 16-lead ceramic dual-in-line packages (D and F suffixes), 16-lead dual-in-line plastic packages (E suffix), 16-lead ceramic flat packages (K suffix), and in chip form (H suffix).

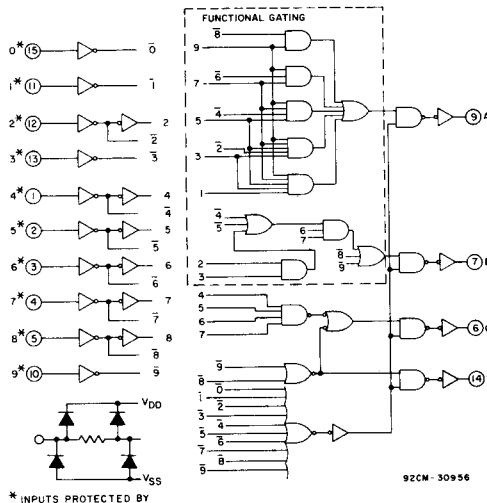


Fig. 1 - CD40147B logic diagram.

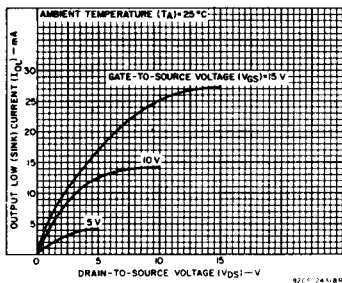


Fig. 2 - Typical output low (sink) current characteristics.

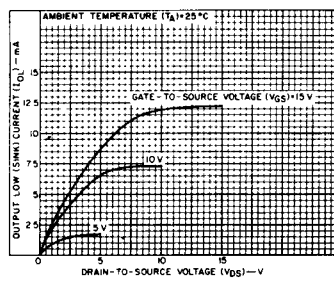


Fig. 3 - Minimum output low (sink) current characteristics.

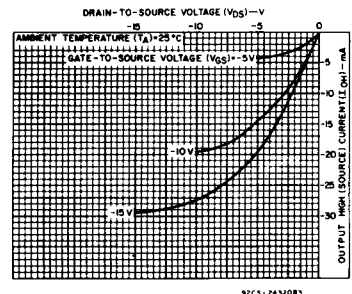


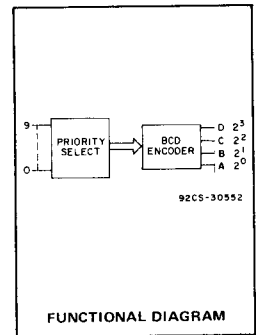
Fig. 4 - Typical output high (source) current characteristics.

### Features:

- Encodes 10-line to 4-line BCD
- Active low inputs and outputs
- Standardized, symmetrical output characteristics
- 100% tested for quiescent current at 20 V
- 5-V, 10-V, and 15-V parametric ratings
- Meets all requirements of JEDEC Tentative Standard No. 13A, "Standard Specifications for Description of 'B' Series CMOS Devices"
- Maximum input current of 1  $\mu$ A at 18 V over full package-temperature range; 100 nA at 18 V and 25°C
- Noise margin (full package-temperature range) =
  - 1 V at  $V_{DD} = 5$  V
  - 2 V at  $V_{DD} = 10$  V
  - 2.5 V at  $V_{DD} = 15$  V

### Applications:

- Keyboard encoding
- 10-line to BCD encoding
- Range selection



### RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following range:

CHARACTERISTIC	LIMITS		UNITS
	Min.	Max.	
Supply Voltage Range (For $T_A =$ Full Package Temperature Range)	3	18	V

### TRUTH TABLE (Negative Logic)

INPUTS										OUTPUTS			
0	1	2	3	4	5	6	7	8	9	D	C	B	A
0	0	0	0	0	0	0	0	0	0	1	1	1	1
1	0	0	0	0	0	0	0	0	0	0	0	0	0
X	1	0	0	0	0	0	0	0	0	0	0	1	0
X	X	1	0	0	0	0	0	0	0	0	0	1	0
X	X	X	1	0	0	0	0	0	0	0	0	1	0
X	X	X	X	1	0	0	0	0	0	0	1	0	0
X	X	X	X	X	1	0	0	0	0	0	1	1	0
X	X	X	X	X	X	1	0	0	0	0	1	1	1
X	X	X	X	X	X	X	1	0	1	0	0	0	0
X	X	X	X	X	X	X	X	1	1	0	0	0	1

0 = High Level      1 = Low Level      X = Don't Care

# CD40147B Types

## MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY-VOLTAGE RANGE, (V<sub>DD</sub>)

Voltages referenced to V<sub>SS</sub> Terminal) ..... -0.5V to +20V

INPUT VOLTAGE RANGE, ALL INPUTS ..... -0.5V to V<sub>DD</sub>+0.5V

DC INPUT CURRENT, ANY ONE INPUT ..... ±10mA

POWER DISSIPATION PER PACKAGE (P<sub>D</sub>):

For T<sub>A</sub> = -55°C to +100°C ..... 500mW

For T<sub>A</sub> = +100°C to +125°C ..... Derate Linearity at 12mW/°C to 200mW

DEVICE DISSIPATION PER OUTPUT TRANSISTOR

FOR T<sub>A</sub> = FULL PACKAGE-TEMPERATURE RANGE (All Package Types) ..... 100mW

OPERATING-TEMPERATURE RANGE (T<sub>A</sub>) ..... -55°C to +125°C

STORAGE TEMPERATURE RANGE (T<sub>stg</sub>) ..... -65°C to +150°C

LEAD TEMPERATURE (DURING SOLDERING):

At distance 1/16 ± 1/32 inch (1.59 ± 0.79mm) from case for 10s max ..... +265°C

## STATIC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)							UNITS
	V <sub>O</sub> (V)	V <sub>IN</sub> (V)	V <sub>DD</sub> (V)	-55	-40	+85	+125	+25			
								Min.	Typ.	Max.	
Quiescent Device Current, I <sub>DD</sub> Max.	—	0.5	5	5	5	150	150	—	0.04	5	μA
Output Low (Sink) Current I <sub>OL</sub> Min.	0.4	0.5	5	0.64	0.61	0.42	0.36	0.51	1	—	
Output Current, I <sub>OH</sub> Min.	—	0.15	15	20	20	600	600	—	0.04	20	mA
Output Current, I <sub>OH</sub> Min.	—	0.20	20	100	100	3000	3000	—	0.08	100	
Output Voltage: Low-Level, V <sub>OL</sub> Max.	—	0.5	5	0.05			0			0.05	V
Output Voltage: High-Level, V <sub>OH</sub> Min.	—	0.15	15	0.05			0			0.05	
Input Low Voltage, V <sub>IL</sub> Max.	0.5, 4.5	—	5	1.5			—			1.5	V
Input High Voltage, V <sub>IH</sub> Min.	1.5, 13.5	—	15	4			—			4	
Input Current I <sub>IN</sub> Max.	—	0.18	18	±0.1	±0.1	±1	±1	—	±10 <sup>-5</sup>	±0.1	μA

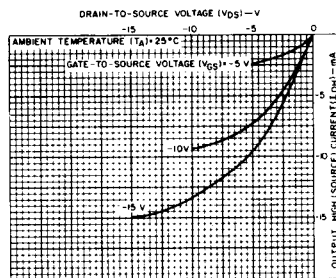


Fig. 5 - Minimum output high (source) current characteristics.

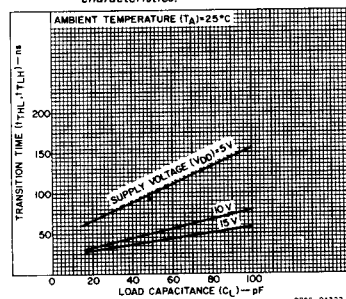


Fig. 6 - Typical transition time as a function of load capacitance.

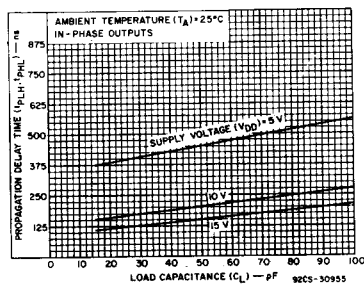


Fig. 7 - Propagation delay time as a function of load capacitance.

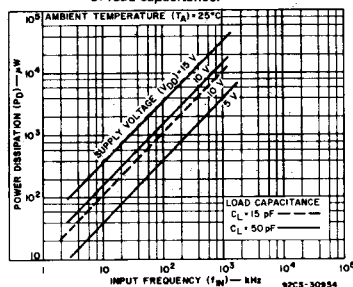


Fig. 8 - Typical dynamic power dissipation as a function of input frequency.

3  
COMMERCIAL CMOS  
HIGH VOLTAGE ICs

## CD40147B Types

**DYNAMIC ELECTRICAL CHARACTERISTICS at  $T_A = 25^\circ\text{C}$ , Input  $t_r, t_f = 20\text{ ns}$ ,  $C_L = 50\text{ pF}$ ,  $R_L = 200\text{ k}\Omega$**

CHARACTERISTIC	TEST CONDITIONS	LIMITS ALL TYPES			UNITS
		V <sub>DD</sub> (V)	Typ.	Max.	
Propagation Delay Time, $t_{PLH}$ , $t_{PHL}$ In-Phase Output	Any input to any output	5	450	900	ns
		10	200	400	
		15	150	300	
Out-of-Phase Output		5	425	850	ns
		10	175	350	
		15	125	250	
Transition Time, $t_{THL}$ , $t_{TLH}$	5	100	200	ns	
	10	50	100		
	15	40	80		
Input Capacitance, $C_1$	Any Input	5	7.5	pF	

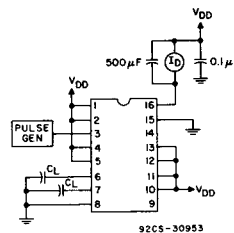


Fig. 9 – Dynamic power dissipation test circuit.

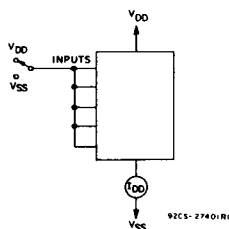


Fig. 10 – Quiescent device current test circuit.

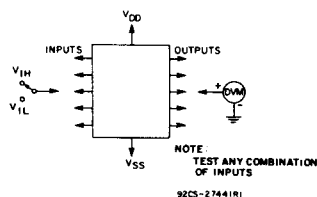


Fig. 11 – Input voltage test circuit.

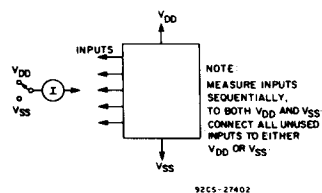
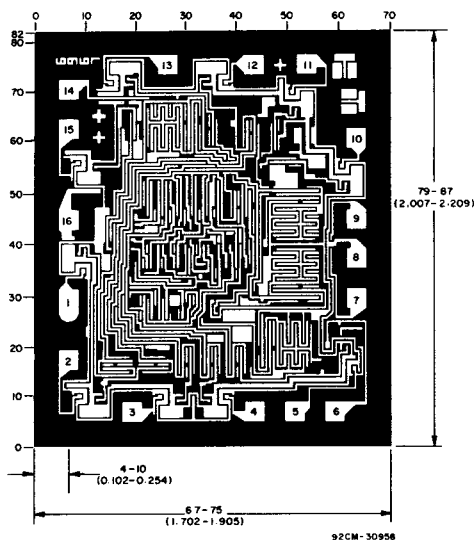
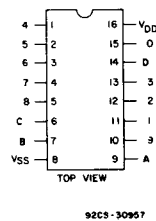


Fig. 12 – Input current test circuit.



Dimensions and pad layout for CD40147BH



**CD40147B  
TERMINAL  
ASSIGNMENT**

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils ( $10^{-3}$  inch).